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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

|                                |                                                                                                                                                                 |
|--------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Product Status                 | Active                                                                                                                                                          |
| Number of LABs/CLBs            | -                                                                                                                                                               |
| Number of Logic Elements/Cells | 12084                                                                                                                                                           |
| Total RAM Bits                 | 933888                                                                                                                                                          |
| Number of I/O                  | 233                                                                                                                                                             |
| Number of Gates                | -                                                                                                                                                               |
| Voltage - Supply               | 1.14V ~ 2.625V                                                                                                                                                  |
| Mounting Type                  | Surface Mount                                                                                                                                                   |
| Operating Temperature          | -40°C ~ 100°C (TJ)                                                                                                                                              |
| Package / Case                 | 484-BGA                                                                                                                                                         |
| Supplier Device Package        | 484-FPBGA (23x23)                                                                                                                                               |
| Purchase URL                   | <a href="https://www.e-xfl.com/product-detail/microchip-technology/m2gl010-fg484i">https://www.e-xfl.com/product-detail/microchip-technology/m2gl010-fg484i</a> |

The following table lists the embedded operating flash limits.

**Table 6 • Embedded Operating Flash Limits**

| Product Grade | Element        | Programming Temperature                                                            | Maximum Operating Temperature                                                      | Programming Cycles                                                    | Retention (Biased/Unbiased) |
|---------------|----------------|------------------------------------------------------------------------------------|------------------------------------------------------------------------------------|-----------------------------------------------------------------------|-----------------------------|
| Commercial    | Embedded flash | Min $T_J = 0\text{ }^{\circ}\text{C}$<br>Max $T_J = 85\text{ }^{\circ}\text{C}$    | Min $T_J = 0\text{ }^{\circ}\text{C}$<br>Max $T_J = 85\text{ }^{\circ}\text{C}$    | < 1000 cycles per page,<br>up to two million cycles<br>per eNVM array | 20 years                    |
|               |                |                                                                                    | Min $T_J = 0\text{ }^{\circ}\text{C}$<br>Max $T_J = 85\text{ }^{\circ}\text{C}$    | < 10000 cycles per page,<br>up to 20 million cycles per<br>eNVM array | 10 years                    |
| Industrial    | Embedded flash | Min $T_J = -40\text{ }^{\circ}\text{C}$<br>Max $T_J = 100\text{ }^{\circ}\text{C}$ | Min $T_J = -40\text{ }^{\circ}\text{C}$<br>Max $T_J = 100\text{ }^{\circ}\text{C}$ | < 1000 cycles per page,<br>up to two million cycles<br>per eNVM array | 20 years                    |
|               |                |                                                                                    | Min $T_J = -40\text{ }^{\circ}\text{C}$<br>Max $T_J = 100\text{ }^{\circ}\text{C}$ | < 10000 cycles per page,<br>up to 20 million cycles per<br>eNVM array | 10 years                    |

**Note:** If your product qualification requires accelerated programming cycles, see *Microsemi SoC Products Quality and Reliability Report* about recommended methodologies.

**Table 7 • Device Storage Temperature and Retention**

| Product Grade | Storage Temperature (Tstg)                                                         | Retention |
|---------------|------------------------------------------------------------------------------------|-----------|
| Commercial    | Min $T_J = 0\text{ }^{\circ}\text{C}$<br>Max $T_J = 85\text{ }^{\circ}\text{C}$    | 20 years  |
| Industrial    | Min $T_J = -40\text{ }^{\circ}\text{C}$<br>Max $T_J = 100\text{ }^{\circ}\text{C}$ | 20 years  |

**Table 8 • High Temperature Data Retention (HTR) Lifetime**

| $T_J$ (C) | HTR Lifetime <sup>1</sup> (yrs) |
|-----------|---------------------------------|
| 90        | 20.5                            |
| 95        | 20.5                            |
| 100       | 20.5                            |
| 105       | 17.0                            |
| 110       | 15.0                            |
| 115       | 13.0                            |
| 120       | 11.5                            |
| 125       | 10.0                            |
| 130       | 8.0                             |
| 135       | 6.0                             |
| 140       | 4.5                             |
| 145       | 3.0                             |
| 150       | 1.5                             |

1. HTR Lifetime is the period during which a verify failure is not expected due to flash leakage.

**Table 15 • Inrush Currents at Power up,  $-40\text{ }^{\circ}\text{C} \leq T_J \leq 100\text{ }^{\circ}\text{C}$  – Typical Process**

| Power Supplies  | Voltage (V) | 005 | 010 | 025 | 050 | 060 | 090 | 150 | Unit |
|-----------------|-------------|-----|-----|-----|-----|-----|-----|-----|------|
| $V_{DD}$        | 1.26        | 25  | 32  | 38  | 48  | 45  | 77  | 109 | mA   |
| $V_{PP}$        | 3.46        | 33  | 49  | 36  | 180 | 13  | 36  | 51  | mA   |
| $V_{DDI}$       | 2.62        | 134 | 141 | 161 | 187 | 93  | 272 | 388 | mA   |
| Number of banks |             | 7   | 8   | 8   | 10  | 10  | 9   | 19  |      |

### 2.3.3 Average Fabric Temperature and Voltage Derating Factors

The following table lists the average temperature and voltage derating factors for fabric timing delays normalized to  $T_J = 85\text{ }^{\circ}\text{C}$ , in worst-case  $V_{DD} = 1.14\text{ V}$ .

**Table 16 • Average Junction Temperature and Voltage Derating Factors for Fabric Timing Delays**

| Array Voltage $V_{DD}$ (V) | $-40\text{ }^{\circ}\text{C}$ | $0\text{ }^{\circ}\text{C}$ | $25\text{ }^{\circ}\text{C}$ | $70\text{ }^{\circ}\text{C}$ | $85\text{ }^{\circ}\text{C}$ | $100\text{ }^{\circ}\text{C}$ |
|----------------------------|-------------------------------|-----------------------------|------------------------------|------------------------------|------------------------------|-------------------------------|
| 1.14                       | 0.83                          | 0.89                        | 0.92                         | 0.98                         | <b>1.00</b>                  | 1.02                          |
| 1.2                        | 0.75                          | 0.80                        | 0.83                         | 0.89                         | 0.91                         | 0.93                          |
| 1.26                       | 0.69                          | 0.73                        | 0.76                         | 0.81                         | 0.83                         | 0.85                          |

### 2.3.5.5 Detailed I/O Characteristics

**Table 24 • Input Capacitance, Leakage Current, and Ramp Time**

| Symbol         | Description                                                    | Maximum | Unit    | Conditions          |
|----------------|----------------------------------------------------------------|---------|---------|---------------------|
| $C_{IN}$       | Input capacitance                                              | 10      | pF      |                     |
| $I_{IL}$ (dc)  | Input current low<br>(Applicable to HSTL/SSTL inputs only)     | 400     | $\mu A$ | $V_{DDI} = 2.5 V$   |
|                |                                                                | 500     | $\mu A$ | $V_{DDI} = 1.8 V$   |
|                |                                                                | 600     | $\mu A$ | $V_{DDI} = 1.5 V^1$ |
|                | Input current low<br>(Applicable to all other digital inputs)  | 10      | $\mu A$ |                     |
| $I_{IH}$ (dc)  | Input current high<br>(Applicable to HSTL/SSTL inputs only)    | 400     | $\mu A$ | $V_{DDI} = 2.5 V$   |
|                |                                                                | 500     | $\mu A$ | $V_{DDI} = 1.8 V$   |
|                |                                                                | 600     | $\mu A$ | $V_{DDI} = 1.5 V^1$ |
|                | Input current high<br>(Applicable to all other digital inputs) | 10      | $\mu A$ |                     |
| $T_{RAMPIN}^2$ | Input ramp time<br>(Applicable to all digital inputs)          | 50      | ns      |                     |

1. Applicable when I/O pair is programmed with an HSTL/SSTL I/O type on IOP and an un-terminated I/O type (LVCMOS, for example) on ION pad.
2. Voltage ramp must be monotonic.

The following table lists the minimum and maximum I/O weak pull-up/pull-down resistance values of DDRIO I/O bank at  $V_{OH}/V_{OL}$  Level.

**Table 25 • I/O Weak Pull-up/Pull-down Resistances for DDRIO I/O Bank**

| $V_{DDI}$ Domain      | R(WEAK PULL-UP) at $V_{OH}$ ( $\Omega$ ) |       | R(WEAK PULL-DOWN) at $V_{OL}$ ( $\Omega$ ) |       |
|-----------------------|------------------------------------------|-------|--------------------------------------------|-------|
|                       | Min                                      | Max   | Min                                        | Max   |
| 2.5 V <sup>1, 2</sup> | 10K                                      | 17.8K | 9.98K                                      | 18K   |
| 1.8 V <sup>1, 2</sup> | 10.3K                                    | 19.1K | 10.3K                                      | 19.5K |
| 1.5 V <sup>1, 2</sup> | 10.6K                                    | 20.2K | 10.6K                                      | 21.1K |
| 1.2 V <sup>1, 2</sup> | 11.1K                                    | 22.7K | 11.2K                                      | 24.6K |

1.  $R(\text{WEAK PULL-DOWN}) = (V_{OLspec})/I(\text{WEAK PULL-DOWN MAX})$ .
2.  $R(\text{WEAK PULL-UP}) = (V_{DDImax} - V_{OHspec})/I(\text{WEAK PULL-UP MIN})$ .

**Table 57 • LVCMOS 1.8 V Transmitter Characteristics for DDRIO I/O Bank with Fixed Code (Output and Tristate Buffers)**

| Output Drive Selection | Slew Control | T <sub>DP</sub> |       | T <sub>ZL</sub> |       | T <sub>ZH</sub> |       | T <sub>HZ</sub> <sup>1</sup> |       | T <sub>LZ</sub> <sup>1</sup> |       | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
|                        |              | -1              | -Std  | -1              | -Std  | -1              | -Std  | -1                           | -Std  | -1                           | -Std  |      |
| 2 mA                   | Slow         | 4.234           | 4.981 | 3.646           | 4.29  | 4.245           | 4.995 | 4.908                        | 5.774 | 4.434                        | 5.216 | ns   |
|                        | Medium       | 3.824           | 4.498 | 3.282           | 3.861 | 3.834           | 4.511 | 4.625                        | 5.441 | 4.116                        | 4.843 | ns   |
|                        | Medium fast  | 3.627           | 4.267 | 3.111           | 3.66  | 3.637           | 4.279 | 4.481                        | 5.272 | 3.984                        | 4.687 | ns   |
|                        | Fast         | 3.605           | 4.241 | 3.097           | 3.644 | 3.615           | 4.253 | 4.472                        | 5.262 | 3.973                        | 4.674 | ns   |
| 4 mA                   | Slow         | 3.923           | 4.615 | 3.314           | 3.9   | 3.918           | 4.61  | 5.403                        | 6.356 | 4.894                        | 5.757 | ns   |
|                        | Medium       | 3.518           | 4.138 | 2.961           | 3.484 | 3.515           | 4.135 | 5.121                        | 6.025 | 4.561                        | 5.366 | ns   |
|                        | Medium fast  | 3.321           | 3.907 | 2.783           | 3.275 | 3.317           | 3.903 | 4.966                        | 5.843 | 4.426                        | 5.206 | ns   |
|                        | Fast         | 3.301           | 3.883 | 2.77            | 3.259 | 3.296           | 3.878 | 4.957                        | 5.831 | 4.417                        | 5.196 | ns   |
| 6 mA                   | Slow         | 3.71            | 4.364 | 3.104           | 3.652 | 3.702           | 4.355 | 5.62                         | 6.612 | 5.08                         | 5.977 | ns   |
|                        | Medium       | 3.333           | 3.921 | 2.779           | 3.27  | 3.325           | 3.913 | 5.346                        | 6.289 | 4.777                        | 5.62  | ns   |
|                        | Medium fast  | 3.155           | 3.712 | 2.62            | 3.083 | 3.146           | 3.702 | 5.21                         | 6.13  | 4.657                        | 5.479 | ns   |
|                        | Fast         | 3.134           | 3.688 | 2.608           | 3.068 | 3.125           | 3.677 | 5.202                        | 6.12  | 4.648                        | 5.468 | ns   |
| 8 mA                   | Slow         | 3.619           | 4.258 | 3.007           | 3.538 | 3.607           | 4.244 | 5.815                        | 6.841 | 5.249                        | 6.175 | ns   |
|                        | Medium       | 3.246           | 3.819 | 2.686           | 3.16  | 3.236           | 3.807 | 5.542                        | 6.52  | 4.936                        | 5.807 | ns   |
|                        | Medium fast  | 3.066           | 3.607 | 2.525           | 2.971 | 3.054           | 3.593 | 5.405                        | 6.359 | 4.811                        | 5.66  | ns   |
|                        | Fast         | 3.046           | 3.584 | 2.513           | 2.957 | 3.034           | 3.57  | 5.401                        | 6.353 | 4.803                        | 5.651 | ns   |
| 10 mA                  | Slow         | 3.498           | 4.115 | 2.878           | 3.386 | 3.481           | 4.096 | 6.046                        | 7.113 | 5.444                        | 6.404 | ns   |
|                        | Medium       | 3.138           | 3.692 | 2.569           | 3.023 | 3.126           | 3.678 | 5.782                        | 6.803 | 5.129                        | 6.034 | ns   |
|                        | Medium fast  | 2.966           | 3.489 | 2.414           | 2.841 | 2.951           | 3.472 | 5.666                        | 6.665 | 5.013                        | 5.897 | ns   |
|                        | Fast         | 2.945           | 3.464 | 2.401           | 2.826 | 2.93            | 3.448 | 5.659                        | 6.658 | 5.003                        | 5.886 | ns   |
| 12 mA                  | Slow         | 3.417           | 4.02  | 2.807           | 3.303 | 3.401           | 4.002 | 6.083                        | 7.156 | 5.464                        | 6.428 | ns   |
|                        | Medium       | 3.076           | 3.618 | 2.519           | 2.964 | 3.063           | 3.604 | 5.828                        | 6.856 | 5.176                        | 6.089 | ns   |
|                        | Medium fast  | 2.913           | 3.427 | 2.376           | 2.795 | 2.898           | 3.41  | 5.725                        | 6.736 | 5.072                        | 5.966 | ns   |
|                        | Fast         | 2.894           | 3.405 | 2.362           | 2.78  | 2.879           | 3.388 | 5.715                        | 6.724 | 5.064                        | 5.957 | ns   |
| 16 mA                  | Slow         | 3.366           | 3.96  | 2.751           | 3.237 | 3.348           | 3.939 | 6.226                        | 7.324 | 5.576                        | 6.56  | ns   |
|                        | Medium       | 3.03            | 3.565 | 2.47            | 2.906 | 3.017           | 3.55  | 5.981                        | 7.036 | 5.282                        | 6.214 | ns   |
|                        | Medium fast  | 2.87            | 3.377 | 2.328           | 2.739 | 2.854           | 3.358 | 5.895                        | 6.935 | 5.18                         | 6.094 | ns   |
|                        | Fast         | 2.853           | 3.357 | 2.314           | 2.723 | 2.837           | 3.338 | 5.889                        | 6.929 | 5.177                        | 6.09  | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 70 • LVCMOS 1.5 V Transmitter Characteristics for DDRIO I/O Bank (Output and Tristate Buffers)**  
(continued)

| Output Drive Selection | Slew Control | T <sub>DP</sub> |       | T <sub>ZL</sub> |       | T <sub>ZH</sub> |       | T <sub>HZ</sub> <sup>1</sup> |       | T <sub>LZ</sub> <sup>1</sup> |       | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
|                        |              | -1              | -Std  | -1              | -Std  | -1              | -Std  | -1                           | -Std  | -1                           | -Std  |      |
| 6 mA                   | Slow         | 4.244           | 4.993 | 3.465           | 4.076 | 4.233           | 4.979 | 6.39                         | 7.518 | 5.736                        | 6.748 | ns   |
|                        | Medium       | 3.774           | 4.44  | 3.05            | 3.587 | 3.762           | 4.426 | 6.114                        | 7.193 | 5.397                        | 6.35  | ns   |
|                        | Medium fast  | 3.544           | 4.17  | 2.839           | 3.339 | 3.529           | 4.152 | 5.978                        | 7.033 | 5.27                         | 6.2   | ns   |
|                        | Fast         | 3.519           | 4.14  | 2.82            | 3.317 | 3.504           | 4.122 | 5.965                        | 7.017 | 5.259                        | 6.187 | ns   |
| 8 mA                   | Slow         | 4.099           | 4.823 | 3.311           | 3.894 | 4.087           | 4.807 | 6.584                        | 7.746 | 5.854                        | 6.888 | ns   |
|                        | Medium       | 3.656           | 4.301 | 2.927           | 3.443 | 3.642           | 4.284 | 6.311                        | 7.425 | 5.553                        | 6.533 | ns   |
|                        | Medium fast  | 3.437           | 4.044 | 2.731           | 3.213 | 3.42            | 4.023 | 6.182                        | 7.273 | 5.435                        | 6.394 | ns   |
|                        | Fast         | 3.41            | 4.012 | 2.715           | 3.193 | 3.393           | 3.991 | 6.178                        | 7.269 | 5.425                        | 6.383 | ns   |
| 10 mA                  | Slow         | 4.029           | 4.74  | 3.238           | 3.809 | 4.015           | 4.723 | 6.732                        | 7.921 | 5.965                        | 7.018 | ns   |
|                        | Medium       | 3.601           | 4.237 | 2.867           | 3.372 | 3.586           | 4.218 | 6.473                        | 7.615 | 5.669                        | 6.669 | ns   |
|                        | Medium fast  | 3.384           | 3.981 | 2.672           | 3.143 | 3.365           | 3.958 | 6.351                        | 7.471 | 5.55                         | 6.529 | ns   |
|                        | Fast         | 3.357           | 3.949 | 2.655           | 3.123 | 3.338           | 3.927 | 6.345                        | 7.464 | 5.54                         | 6.518 | ns   |
| 12 mA                  | Slow         | 3.974           | 4.675 | 3.196           | 3.759 | 3.958           | 4.656 | 6.842                        | 8.049 | 6.068                        | 7.139 | ns   |
|                        | Medium       | 3.55            | 4.176 | 2.827           | 3.326 | 3.534           | 4.157 | 6.584                        | 7.746 | 5.751                        | 6.766 | ns   |
|                        | Medium fast  | 3.345           | 3.935 | 2.638           | 3.103 | 3.325           | 3.911 | 6.488                        | 7.633 | 5.641                        | 6.637 | ns   |
|                        | Fast         | 3.316           | 3.902 | 2.621           | 3.083 | 3.297           | 3.878 | 6.486                        | 7.63  | 5.626                        | 6.619 | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 71 • LVCMOS 1.5 V Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)**

| Output Drive Selection | Slew Control | T <sub>DP</sub> |       | T <sub>ZL</sub> |       | T <sub>ZH</sub> |       | T <sub>HZ</sub> <sup>1</sup> |       | T <sub>LZ</sub> <sup>1</sup> |       | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
|                        |              | -1              | -Std  | -1              | -Std  | -1              | -Std  | -1                           | -Std  | -1                           | -Std  |      |
| 2 mA                   | Slow         | 4.423           | 5.203 | 5.397           | 6.35  | 5.686           | 6.69  | 5.609                        | 6.599 | 5.561                        | 6.542 | ns   |
| 4 mA                   | Slow         | 4.05            | 4.765 | 4.503           | 5.298 | 4.92            | 5.788 | 7.358                        | 8.657 | 6.525                        | 7.677 | ns   |
| 6 mA                   | Slow         | 4.081           | 4.801 | 4.259           | 5.012 | 4.699           | 5.528 | 7.659                        | 9.011 | 6.709                        | 7.893 | ns   |
| 8 mA                   | Slow         | 4.234           | 4.98  | 4.068           | 4.786 | 4.521           | 5.319 | 8.218                        | 9.668 | 7.05                         | 8.294 | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**AC Switching Characteristics**

Worst commercial-case conditions:  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 3.0\text{ V}$

**Table 91 • PCI/PCIX AC Switching Characteristics for Receiver for MSIO I/O Bank (Input Buffers)**

| On-Die Termination (ODT) | $T_{PY}$ |       | $T_{PYS}$ |       | Unit |
|--------------------------|----------|-------|-----------|-------|------|
|                          | -1       | -Std  | -1        | -Std  |      |
| None                     | 2.229    | 2.623 | 2.238     | 2.633 | ns   |

**Table 92 • PCI/PCIX AC switching Characteristics for Transmitter for MSIO I/O Bank (Output and Tristate Buffers)**

| $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}$ |       | $T_{LZ}$ |       | Unit |
|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  |      |
| 2.146    | 2.525 | 2.043    | 2.404 | 2.084    | 2.452 | 6.095    | 7.171 | 5.558    | 6.539 | ns   |

### 2.3.6 Memory Interface and Voltage Referenced I/O Standards

This section describes High-Speed Transceiver Logic (HSTL) memory interface and voltage reference I/O standards.

#### 2.3.6.1 High-Speed Transceiver Logic (HSTL)

The HSTL standard is a general purpose high-speed bus standard sponsored by IBM (EIA/JESD8-6). IGLOO2 FPGA and SmartFusion2 SoC FPGA devices support two classes of the 1.5 V HSTL. These differential versions of the standard require a differential amplifier input buffer and a push-pull output buffer.

**Minimum and Maximum DC/AC Input and Output Levels Specification (Applicable to DDRIO Bank Only)**

**Table 93 • HSTL Recommended DC Operating Conditions**

| Parameter               | Symbol    | Min   | Typ   | Max   | Unit |
|-------------------------|-----------|-------|-------|-------|------|
| Supply voltage          | $V_{DDI}$ | 1.425 | 1.5   | 1.575 | V    |
| Termination voltage     | $V_{TT}$  | 0.698 | 0.750 | 0.803 | V    |
| Input reference voltage | $V_{REF}$ | 0.698 | 0.750 | 0.803 | V    |

**Table 94 • HSTL DC Input Voltage Specification**

| Parameter                       | Symbol              | Min             | Max             | Unit |
|---------------------------------|---------------------|-----------------|-----------------|------|
| DC input logic high             | $V_{IH}(\text{DC})$ | $V_{REF} + 0.1$ | 1.575           | V    |
| DC input logic low              | $V_{IL}(\text{DC})$ | -0.3            | $V_{REF} - 0.1$ | V    |
| Input current high <sup>1</sup> | $I_{IH}(\text{DC})$ |                 |                 |      |
| Input current low <sup>1</sup>  | $I_{IL}(\text{DC})$ |                 |                 |      |

1. See Table 24, page 22.

**Table 122 • SSTL18 DC Differential Voltage Specification**

| Parameter                     | Symbol        | Min | Unit |
|-------------------------------|---------------|-----|------|
| DC input differential voltage | $V_{ID}$ (DC) | 0.3 | V    |

**Table 123 • SSTL18 AC Differential Voltage Specifications (Applicable to DDRIO Bank Only)**

| Parameter                           | Symbol          | Min                          | Max                          | Unit |
|-------------------------------------|-----------------|------------------------------|------------------------------|------|
| AC input differential voltage       | $V_{DIFF}$ (AC) | 0.5                          |                              | V    |
| AC differential cross point voltage | $V_x$ (AC)      | $0.5 \times V_{DDI} - 0.175$ | $0.5 \times V_{DDI} + 0.175$ | V    |

**Table 124 • SSTL18 Minimum and Maximum AC Switching Speed (Applicable to DDRIO Bank Only)**

| Parameter                              | Symbol    | Max | Unit | Conditions                          |
|----------------------------------------|-----------|-----|------|-------------------------------------|
| Maximum data rate (for DDRIO I/O bank) | $D_{MAX}$ | 667 | Mbps | AC loading: per JEDEC specification |

**Table 125 • SSTL18 AC Impedance Specifications (Applicable to DDRIO Bank Only)**

| Parameter                                                         | Symbol    | Typ         | Unit     | Conditions                        |
|-------------------------------------------------------------------|-----------|-------------|----------|-----------------------------------|
| Supported output driver calibrated impedance (for DDRIO I/O bank) | $R_{REF}$ | 20, 42      | $\Omega$ | Reference resistor = 150 $\Omega$ |
| Effective impedance value (ODT)                                   | $R_{TT}$  | 50, 75, 150 | $\Omega$ | Reference resistor = 150 $\Omega$ |

**Table 126 • SSTL18 AC Test Parameter Specifications (Applicable to DDRIO Bank Only)**

| Parameter                                                                        | Symbol      | Typ | Unit     |
|----------------------------------------------------------------------------------|-------------|-----|----------|
| Measuring/trip point for data path                                               | $V_{TRIP}$  | 0.9 | V        |
| Resistance for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )         | $R_{ENT}$   | 2K  | $\Omega$ |
| Capacitive loading for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ ) | $C_{ENT}$   | 5   | pF       |
| Reference resistance for data test path for SSTL18 Class I ( $T_{DP}$ )          | $RTT\_TEST$ | 50  | $\Omega$ |
| Reference resistance for data test path for SSTL18 Class II ( $T_{DP}$ )         | $RTT\_TEST$ | 25  | $\Omega$ |
| Capacitive loading for data path ( $T_{DP}$ )                                    | $C_{LOAD}$  | 5   | pF       |

**AC Switching Characteristics**

Worst commercial-case conditions:  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 1.71\text{ V}$

**Table 127 • DDR2/SSTL18 Receiver Characteristics for DDRIO I/O Bank with Fixed Code**

|                     |      | $T_{PY}$ |       | Unit |
|---------------------|------|----------|-------|------|
|                     |      | -1       | -Std  |      |
| Pseudo differential | None | 1.567    | 1.844 | ns   |
| True differential   | None | 1.588    | 1.869 | ns   |

**Table 198 • Mini-LVDS AC Impedance Specifications**

| Parameter              | Symbol | Typ | Unit     |
|------------------------|--------|-----|----------|
| Termination resistance | $R_T$  | 100 | $\Omega$ |

**Table 199 • Mini-LVDS AC Test Parameter Specifications**

| Parameter                                                                        | Symbol     | Typ         | Unit     |
|----------------------------------------------------------------------------------|------------|-------------|----------|
| Measuring/trip point for data path                                               | $V_{TRIP}$ | Cross point | V        |
| Resistance for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )         | $R_{ENT}$  | 2K          | $\Omega$ |
| Capacitive loading for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ ) | $C_{ENT}$  | 5           | pF       |

**AC Switching Characteristics**

Worst commercial-case conditions:  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 2.375\text{ V}$ .

**Table 200 • Mini-LVDS AC Switching Characteristics for Receiver (for MSIO I/O Bank - Input Buffers)**

| On-Die Termination (ODT) | $T_{PY}$ |       | Unit |
|--------------------------|----------|-------|------|
|                          | -1       | -Std  |      |
| None                     | 2.855    | 3.359 | ns   |
| 100                      | 2.85     | 3.353 | ns   |
| None                     | 2.602    | 3.061 | ns   |
| 100                      | 2.597    | 3.055 | ns   |

**Table 201 • Mini-LVDS AC Switching Characteristics for Transmitter for MSIO I/O Bank (Output and Tristate Buffers)**

| $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}$ |      | $T_{LZ}$ |       | Unit |
|----------|-------|----------|-------|----------|-------|----------|------|----------|-------|------|
| -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std | -1       | -Std  |      |
| 2.097    | 2.467 | 2.308    | 2.715 | 2.296    | 2.701 | 1.964    | 2.31 | 1.949    | 2.293 | ns   |

**Table 202 • Mini-LVDS AC Switching Characteristics for Transmitter (for MSIOD I/O Bank - Output and Tristate Buffers)**

|                  | $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}$ |       | $T_{LZ}$ |       | Unit |
|------------------|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
|                  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  |      |
| No pre-emphasis  | 1.614    | 1.899 | 1.562    | 1.837 | 1.553    | 1.826 | 1.593    | 1.874 | 1.578    | 1.856 | ns   |
| Min pre-emphasis | 1.604    | 1.887 | 1.745    | 2.053 | 1.731    | 2.036 | 1.892    | 2.225 | 1.861    | 2.189 | ns   |
| Med pre-emphasis | 1.521    | 1.79  | 1.753    | 2.062 | 1.737    | 2.043 | 1.9      | 2.235 | 1.868    | 2.197 | ns   |
| Max pre-emphasis | 1.492    | 1.754 | 1.762    | 2.073 | 1.745    | 2.052 | 1.91     | 2.247 | 1.876    | 2.206 | ns   |

### 2.3.7.5 RSDS

Reduced Swing Differential Signaling (RSDS) is similar to an LVDS high-speed interface using differential signaling. RSDS has a similar implementation to LVDS devices and is only intended for point-to-point applications.

#### Minimum and Maximum Input and Output Levels

**Table 203 • RSDS Recommended DC Operating Conditions**

| Parameter      | Symbol    | Min   | Typ | Max   | Unit |
|----------------|-----------|-------|-----|-------|------|
| Supply voltage | $V_{DDI}$ | 2.375 | 2.5 | 2.625 | V    |

**Table 204 • RSDS DC Input Voltage Specification**

| Parameter        | Symbol | Min | Max   | Unit |
|------------------|--------|-----|-------|------|
| DC input voltage | $V_I$  | 0   | 2.925 | V    |

**Table 205 • RSDS DC Output Voltage Specification**

| Parameter            | Symbol   | Min  | Typ   | Max  | Unit |
|----------------------|----------|------|-------|------|------|
| DC output logic high | $V_{OH}$ | 1.25 | 1.425 | 1.6  | V    |
| DC output logic low  | $V_{OL}$ | 0.9  | 1.075 | 1.25 | V    |

**Table 206 • RSDS Differential Voltage Specification**

| Parameter                         | Symbol    | Min | Max | Unit |
|-----------------------------------|-----------|-----|-----|------|
| Differential output voltage swing | $V_{OD}$  | 100 | 600 | mV   |
| Output common mode voltage        | $V_{OCM}$ | 0.5 | 1.5 | V    |
| Input common mode voltage         | $V_{ICM}$ | 0.3 | 1.5 | V    |
| Input differential voltage        | $V_{ID}$  | 100 | 600 | mV   |

**Table 207 • RSDS Minimum and Maximum AC Switching Speed**

| Parameter                              | Symbol    | Max | Unit | Conditions                                        |
|----------------------------------------|-----------|-----|------|---------------------------------------------------|
| Maximum data rate (for MSIO I/O bank)  | $D_{MAX}$ | 520 | Mbps | AC loading: 2 pF / 100 $\Omega$ differential load |
| Maximum data rate (for MSIOD I/O bank) | $D_{MAX}$ | 700 | Mbps | AC loading: 2 pF / 100 $\Omega$ differential load |

**Table 208 • RSDS AC Impedance Specifications**

| Parameter              | Symbol | Typ | Unit     |
|------------------------|--------|-----|----------|
| Termination resistance | $R_T$  | 100 | $\Omega$ |

**Table 209 • RSDS AC Test Parameter Specifications**

| Parameter                                                                        | Symbol     | Typ         | Unit     |
|----------------------------------------------------------------------------------|------------|-------------|----------|
| Measuring/trip point for data path                                               | $V_{TRIP}$ | Cross point | V        |
| Resistance for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )         | $R_{ENT}$  | 2K          | $\Omega$ |
| Capacitive loading for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ ) | $C_{ENT}$  | 5           | pF       |

**Table 215 • LVPECL DC Input Voltage Specification**

| Parameter        | Symbol | Min | Max  | Unit |
|------------------|--------|-----|------|------|
| DC input voltage | $V_I$  | 0   | 3.45 | V    |

**Table 216 • LVPECL DC Differential Voltage Specification**

| Parameter                  | Symbol      | Min | Typ | Max   | Unit |
|----------------------------|-------------|-----|-----|-------|------|
| Input common mode voltage  | $V_{ICM}$   | 0.3 |     | 2.8   | V    |
| Input differential voltage | $V_{IDIFF}$ | 100 | 300 | 1,000 | mV   |

**Table 217 • LVPECL Minimum and Maximum AC Switching Speeds**

| Parameter         | Symbol    | Max | Unit |
|-------------------|-----------|-----|------|
| Maximum data rate | $D_{MAX}$ | 900 | Mbps |

**AC Switching Characteristics**

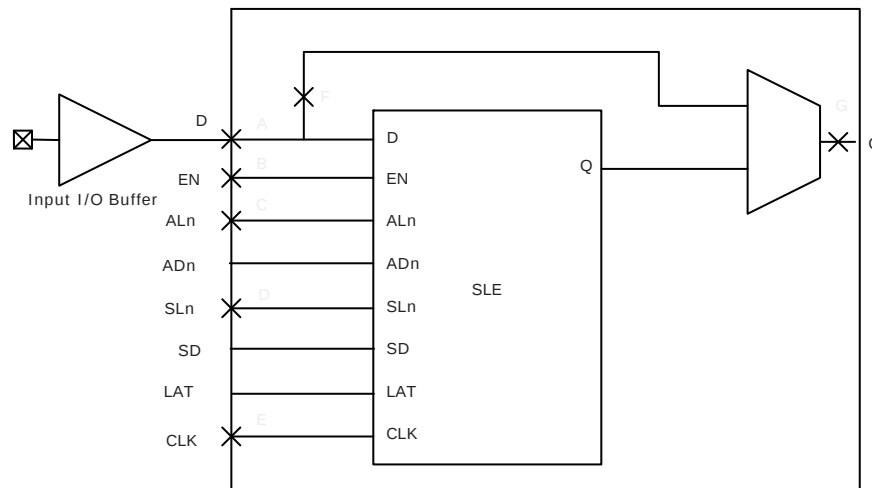
Worst commercial-case conditions:  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 2.375\text{ V}$ .

**Table 218 • LVPECL Receiver Characteristics for MSIO I/O Bank**

| On-Die Termination (ODT) | $T_{PY}$ |       | Unit |
|--------------------------|----------|-------|------|
|                          | -1       | -Std  |      |
| None                     | 2.572    | 3.025 | ns   |
| 100                      | 2.569    | 3.023 | ns   |

**2.3.8 I/O Register Specifications**

This section describes input and output register specifications.

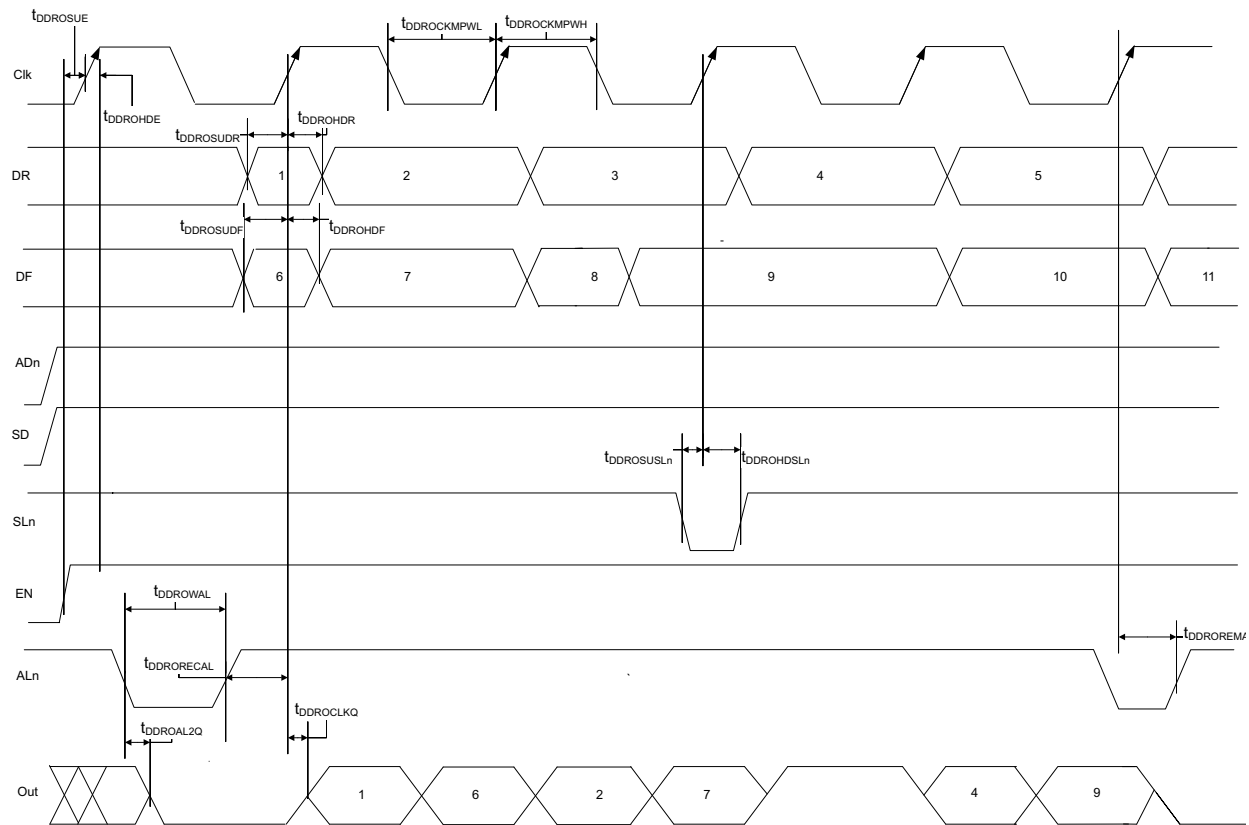
**2.3.8.1 Input Register****Figure 6 • Timing Model for Input Register**

The following table lists the input data register propagation delays in worst commercial-case conditions when  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 219 • Input Data Register Propagation Delays**

| Parameter                                                    | Symbol        | Measuring Nodes (from, to) <sup>1</sup> | -1    | -Std  | Unit |
|--------------------------------------------------------------|---------------|-----------------------------------------|-------|-------|------|
| Bypass delay of the input register                           | $T_{IBYP}$    | F, G                                    | 0.353 | 0.415 | ns   |
| Clock-to-Q of the input register                             | $T_{ICLKQ}$   | E, G                                    | 0.16  | 0.188 | ns   |
| Data setup time for the input register                       | $T_{ISUD}$    | A, E                                    | 0.357 | 0.421 | ns   |
| Data hold time for the input register                        | $T_{IHD}$     | A, E                                    | 0     | 0     | ns   |
| Enable setup time for the input register                     | $T_{ISUE}$    | B, E                                    | 0.46  | 0.542 | ns   |
| Enable hold time for the input register                      | $T_{IHE}$     | B, E                                    | 0     | 0     | ns   |
| Synchronous load setup time for the input register           | $T_{ISUSL}$   | D, E                                    | 0.46  | 0.542 | ns   |
| Synchronous load hold time for the input register            | $T_{IHSL}$    | D, E                                    | 0     | 0     | ns   |
| Asynchronous clear-to-Q of the input register (ADn=1)        | $T_{IALN2Q}$  | C, G                                    | 0.625 | 0.735 | ns   |
| Asynchronous preset-to-Q of the input register (ADn=0)       |               | C, G                                    | 0.587 | 0.69  | ns   |
| Asynchronous load removal time for the input register        | $T_{IREMALN}$ | C, E                                    | 0     | 0     | ns   |
| Asynchronous load recovery time for the input register       | $T_{IRECALN}$ | C, E                                    | 0.074 | 0.087 | ns   |
| Asynchronous load minimum pulse width for the input register | $T_{IWALN}$   | C, C                                    | 0.304 | 0.357 | ns   |
| Clock minimum pulse width high for the input register        | $T_{ICKMPWH}$ | E, E                                    | 0.075 | 0.088 | ns   |
| Clock minimum pulse width low for the input register         | $T_{ICKMPWL}$ | E, E                                    | 0.159 | 0.187 | ns   |

1. For the derating values at specific junction temperature and voltage supply levels, see Table 16, page 14 for derating values.

**Figure 13 • Output DDR Timing Diagram****2.3.9.5 Timing Characteristics**

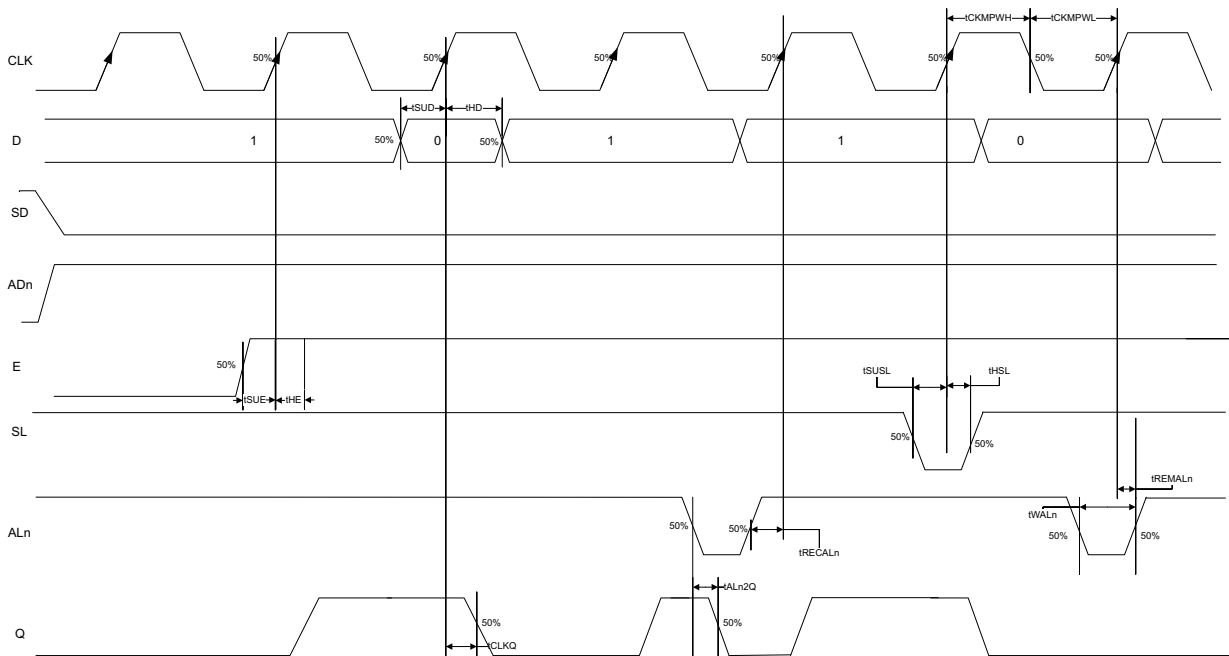
The following table lists the output DDR propagation delays in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 222 • Output DDR Propagation Delays**

| Symbol          | Description                                    | Measuring Nodes<br>(from, to) | -1    | -Std  | Unit |
|-----------------|------------------------------------------------|-------------------------------|-------|-------|------|
| $T_{DDROCKLQ}$  | Clock-to-out of DDR for output DDR             | E, G                          | 0.263 | 0.309 | ns   |
| $T_{DDROSUDF}$  | Data_F data setup for output DDR               | F, E                          | 0.143 | 0.168 | ns   |
| $T_{DDROSUDR}$  | Data_R data setup for output DDR               | A, E                          | 0.19  | 0.223 | ns   |
| $T_{DDROHDF}$   | Data_F data hold for output DDR                | F, E                          | 0     | 0     | ns   |
| $T_{DDROHDR}$   | Data_R data hold for output DDR                | A, E                          | 0     | 0     | ns   |
| $T_{DDROSUE}$   | Enable setup for input DDR                     | B, E                          | 0.419 | 0.493 | ns   |
| $T_{DDROHE}$    | Enable hold for input DDR                      | B, E                          | 0     | 0     | ns   |
| $T_{DDROSUSLn}$ | Synchronous load setup for input DDR           | D, E                          | 0.196 | 0.231 | ns   |
| $T_{DDROHSLn}$  | Synchronous load hold for input DDR            | D, E                          | 0     | 0     | ns   |
| $T_{DDROAL2Q}$  | Asynchronous load-to-out for output DDR        | C, G                          | 0.528 | 0.621 | ns   |
| $T_{DDROREML}$  | Asynchronous load removal time for output DDR  | C, E                          | 0     | 0     | ns   |
| $T_{DDRORECAL}$ | Asynchronous load recovery time for output DDR | C, E                          | 0.034 | 0.04  | ns   |

The following figure shows a configuration with SD = 0 (synchronous clear) and ADn = 1 (asynchronous clear) for a flip-flop (LAT = 0).

**Figure 16 • Sequential Module Timing Diagram**



### 2.3.10.3.1 Timing Characteristics

The following table lists the register delays in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 224 • Register Delays**

| Parameter                                                   | Symbol       | -1    | -Std  | Unit |
|-------------------------------------------------------------|--------------|-------|-------|------|
| Clock-to-Q of the core register                             | $T_{CLKQ}$   | 0.108 | 0.127 | ns   |
| Data setup time for the core register                       | $T_{SUD}$    | 0.254 | 0.298 | ns   |
| Data hold time for the core register                        | $T_{HD}$     | 0     | 0     | ns   |
| Enable setup time for the core register                     | $T_{SUE}$    | 0.335 | 0.394 | ns   |
| Enable hold time for the core register                      | $T_{HE}$     | 0     | 0     | ns   |
| Synchronous load setup time for the core register           | $T_{SUSL}$   | 0.335 | 0.394 | ns   |
| Synchronous load hold time for the core register            | $T_{HSL}$    | 0     | 0     | ns   |
| Asynchronous Clear-to-Q of the core register (ADn = 1)      | $T_{ALN2Q}$  | 0.473 | 0.556 | ns   |
| Asynchronous preset-to-Q of the core register (ADn = 0)     |              | 0.451 | 0.531 | ns   |
| Asynchronous load removal time for the core register        | $T_{RECALN}$ | 0     | 0     | ns   |
| Asynchronous load recovery time for the core register       | $T_{RECALN}$ | 0.353 | 0.415 | ns   |
| Asynchronous load minimum pulse width for the core register | $T_{WALN}$   | 0.266 | 0.313 | ns   |
| Clock minimum pulse width high for the core register        | $T_{CKMPWH}$ | 0.065 | 0.077 | ns   |
| Clock minimum pulse width low for the core register         | $T_{CKMPWL}$ | 0.139 | 0.164 | ns   |

**Table 231 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 1K × 18 (continued)**

| Parameter                                                              | Symbol                | –1     |       | –Std   |       | Unit |
|------------------------------------------------------------------------|-----------------------|--------|-------|--------|-------|------|
|                                                                        |                       | Min    | Max   | Min    | Max   |      |
| Block select hold time                                                 | T <sub>BLKHD</sub>    | 0.216  |       | 0.254  |       | ns   |
| Block select to out disable time (when pipelined register is disabled) | T <sub>BLK2Q</sub>    |        | 1.529 |        | 1.799 | ns   |
| Block select minimum pulse width                                       | T <sub>BLKMPW</sub>   | 0.186  |       | 0.219  |       | ns   |
| Read enable setup time                                                 | T <sub>RDESU</sub>    | 0.449  |       | 0.528  |       | ns   |
| Read enable hold time                                                  | T <sub>RDEHD</sub>    | 0.167  |       | 0.197  |       | ns   |
| Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)                | T <sub>RDPLESU</sub>  | 0.248  |       | 0.291  |       | ns   |
| Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)                 | T <sub>RDPLEHD</sub>  | 0.102  |       | 0.12   |       | ns   |
| Asynchronous reset to output propagation delay                         | T <sub>R2Q</sub>      | –      | 1.506 | –      | 1.772 | ns   |
| Asynchronous reset removal time                                        | T <sub>RSTREM</sub>   | 0.506  |       | 0.595  |       | ns   |
| Asynchronous reset recovery time                                       | T <sub>RSTREC</sub>   | 0.004  |       | 0.005  |       | ns   |
| Asynchronous reset minimum pulse width                                 | T <sub>RSTMPW</sub>   | 0.301  |       | 0.354  |       | ns   |
| Pipelined register asynchronous reset removal time                     | T <sub>PLRSTREM</sub> | –0.279 |       | –0.328 |       | ns   |
| Pipelined register asynchronous reset recovery time                    | T <sub>PLRSTREC</sub> | 0.327  |       | 0.385  |       | ns   |
| Pipelined register asynchronous reset minimum pulse width              | T <sub>PLRSTMPW</sub> | 0.282  |       | 0.332  |       | ns   |
| Synchronous reset setup time                                           | T <sub>SRSTSU</sub>   | 0.226  |       | 0.265  |       | ns   |
| Synchronous reset hold time                                            | T <sub>SRSTHD</sub>   | 0.036  |       | 0.043  |       | ns   |
| Write enable setup time                                                | T <sub>WESU</sub>     | 0.39   |       | 0.458  |       | ns   |
| Write enable hold time                                                 | T <sub>WEHD</sub>     | 0.242  |       | 0.285  |       | ns   |
| Maximum frequency                                                      | F <sub>MAX</sub>      |        | 400   |        | 340   | MHz  |

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 2K × 9 in worst commercial-case conditions when T<sub>J</sub> = 85 °C, V<sub>DD</sub> = 1.14 V.

**Table 232 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 2K × 9**

| Parameter                                  | Symbol                 | –1    |       | –Std  |       | Unit |
|--------------------------------------------|------------------------|-------|-------|-------|-------|------|
|                                            |                        | Min   | Max   | Min   | Max   |      |
| Clock period                               | T <sub>CY</sub>        | 2.5   |       | 2.941 |       | ns   |
| Clock minimum pulse width high             | T <sub>CLKMPWH</sub>   | 1.125 |       | 1.323 |       | ns   |
| Clock minimum pulse width low              | T <sub>CLKMPWL</sub>   | 1.125 |       | 1.323 |       | ns   |
| Pipelined clock period                     | T <sub>PLCY</sub>      | 2.5   |       | 2.941 |       | ns   |
| Pipelined clock minimum pulse width high   | T <sub>PLCLKMPWH</sub> | 1.125 |       | 1.323 |       | ns   |
| Pipelined clock minimum pulse width low    | T <sub>PLCLKMPWL</sub> | 1.125 |       | 1.323 |       | ns   |
| Read access time with pipeline register    |                        |       | 0.334 |       | 0.393 | ns   |
| Read access time without pipeline register | T <sub>CLK2Q</sub>     |       | 2.273 |       | 2.674 | ns   |
| Access time with feed-through write timing |                        |       | 1.529 |       | 1.799 | ns   |

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 16K × 1 in worst commercial-case conditions when  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 235 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 16K × 1**

| Parameter                                                              | Symbol          | –1     |       | –Std   |       | Unit |
|------------------------------------------------------------------------|-----------------|--------|-------|--------|-------|------|
|                                                                        |                 | Min    | Max   | Min    | Max   |      |
| Clock period                                                           | $T_{CY}$        | 2.5    |       | 2.941  |       | ns   |
| Clock minimum pulse width high                                         | $T_{CLKMPWH}$   | 1.125  |       | 1.323  |       | ns   |
| Clock minimum pulse width low                                          | $T_{CLKMPWL}$   | 1.125  |       | 1.323  |       | ns   |
| Pipelined clock period                                                 | $T_{PLCY}$      | 2.5    |       | 2.941  |       | ns   |
| Pipelined clock minimum pulse width high                               | $T_{PLCLKMPWH}$ | 1.125  |       | 1.323  |       | ns   |
| Pipelined clock minimum pulse width low                                | $T_{PLCLKMPWL}$ | 1.125  |       | 1.323  |       | ns   |
| Read access time with pipeline register                                |                 |        | 0.32  |        | 0.377 | ns   |
| Read access time without pipeline register                             | $T_{CLK2Q}$     |        | 2.269 |        | 2.669 | ns   |
| Access time with feed-through write timing                             |                 |        | 1.51  |        | 1.777 | ns   |
| Address setup time                                                     | $T_{ADDRSU}$    | 0.626  |       | 0.737  |       | ns   |
| Address hold time                                                      | $T_{ADDRHD}$    | 0.274  |       | 0.322  |       | ns   |
| Data setup time                                                        | $T_{DSU}$       | 0.322  |       | 0.378  |       | ns   |
| Data hold time                                                         | $T_{DHD}$       | 0.082  |       | 0.096  |       | ns   |
| Block select setup time                                                | $T_{BLKSU}$     | 0.207  |       | 0.244  |       | ns   |
| Block select hold time                                                 | $T_{BLKHD}$     | 0.216  |       | 0.254  |       | ns   |
| Block select to out disable time (when pipelined register is disabled) | $T_{BLK2Q}$     |        | 1.51  |        | 1.777 | ns   |
| Block select minimum pulse width                                       | $T_{BLKMPW}$    | 0.186  |       | 0.219  |       | ns   |
| Read enable setup time                                                 | $T_{RDESU}$     | 0.53   |       | 0.624  |       | ns   |
| Read enable hold time                                                  | $T_{RDEHD}$     | 0.071  |       | 0.083  |       | ns   |
| Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)                | $T_{RDPLESU}$   | 0.248  |       | 0.291  |       | ns   |
| Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)                 | $T_{RDPLEHD}$   | 0.102  |       | 0.12   |       | ns   |
| Asynchronous reset to output propagation delay                         | $T_{R2Q}$       |        | 1.547 |        | 1.82  | ns   |
| Asynchronous reset removal time                                        | $T_{RSTREM}$    | 0.506  |       | 0.595  |       | ns   |
| Asynchronous reset recovery time                                       | $T_{RSTREC}$    | 0.004  |       | 0.005  |       | ns   |
| Asynchronous reset minimum pulse width                                 | $T_{RSTMPW}$    | 0.301  |       | 0.354  |       | ns   |
| Pipelined register asynchronous reset removal time                     | $T_{PLRSTREM}$  | –0.279 |       | –0.328 |       | ns   |
| Pipelined register asynchronous reset recovery time                    | $T_{PLRSTREC}$  | 0.327  |       | 0.385  |       | ns   |
| Pipelined register asynchronous reset minimum pulse width              | $T_{PLRSTMPW}$  | 0.282  |       | 0.332  |       | ns   |
| Synchronous reset setup time                                           | $T_{SRSTSU}$    | 0.226  |       | 0.265  |       | ns   |
| Synchronous reset hold time                                            | $T_{SRSTHD}$    | 0.036  |       | 0.043  |       | ns   |
| Write enable setup time                                                | $T_{WESU}$      | 0.454  |       | 0.534  |       | ns   |
| Write enable hold time                                                 | $T_{WEHD}$      | 0.048  |       | 0.057  |       | ns   |
| Maximum frequency                                                      | $F_{MAX}$       |        | 400   |        | 340   | MHz  |

## 2.3.16 SRAM PUF

For more details on static random-access memory (SRAM) physical unclonable functions (PUF) services, see *AC434: Using SRAM PUF System Service in SmartFusion2 Application Note*.

The following table lists the SRAM PUF in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 274 • SRAM PUF**

| Service                  | PUF Off |        | PUF On |        | Unit |
|--------------------------|---------|--------|--------|--------|------|
|                          | Typ     | Max    | Typ    | Max    |      |
| Create activation code   | 709.1   | 746.4  | 754.4  | 762.5  | ms   |
| Delete activation code   | 1329.3  | 1399.3 | 1414.1 | 1429.3 | ms   |
| Create intrinsic keycode | 656.6   | 691.1  | 698.5  | 706.0  | ms   |
| Create extrinsic keycode | 656.6   | 691.1  | 698.5  | 706.0  | ms   |
| Get number of keys       | 1.3     | 1.4    | 1.4    | 1.4    | ms   |
| Export (Kc0, Kc1)        | 998.0   | 1050.5 | 1061.7 | 1073.1 | ms   |
| Export 2 keycodes        | 2020.2  | 2126.5 | 2149.2 | 2172.3 | ms   |
| Export 4 keycodes        | 3065.7  | 3227.0 | 3261.3 | 3296.4 | ms   |
| Export 8 keycodes        | 5101.0  | 5369.5 | 5426.6 | 5485.0 | ms   |
| Export 16 keycodes       | 9212.1  | 9697.0 | 9800.1 | 9905.5 | ms   |
| Import (Kc0, Kc1)        | 39.7    | 41.8   | 42.2   | 42.7   | ms   |
| Import 2 keycodes        | 50.1    | 52.7   | 53.3   | 53.9   | ms   |
| Import 4 keycodes        | 60.6    | 63.8   | 64.5   | 65.2   | ms   |
| Import 8 keycodes        | 80.9    | 85.1   | 86.1   | 87.0   | ms   |
| Import 16 keycodes       | 123.8   | 130.4  | 131.7  | 133.2  | ms   |
| Delete keycode           | 552.5   | 581.6  | 587.8  | 594.1  | ms   |
| Fetch key                | 31.4    | 33.0   | 33.4   | 33.7   | ms   |
| Fetch ecc key            | 20.0    | 21.1   | 21.3   | 21.5   | ms   |
| Get seed                 | 2.0     | 2.1    | 2.2    | 2.2    | ms   |

**Table 276 • Cryptographic Block Characteristics (continued)**

| Service                  | Conditions | Timing | Unit |
|--------------------------|------------|--------|------|
| SHA256                   | 512 bits   | 540    | kbps |
|                          | 1024 bits  | 780    | kbps |
|                          | 2048 bits  | 950    | kbps |
|                          | 24 kbits   | 1140   | kbps |
| HMAC                     | 512 bytes  | 820    | kbps |
|                          | 1024 bytes | 890    | kbps |
|                          | 2048 bytes | 930    | kbps |
|                          | 24 kbytes  | 980    | kbps |
| KeyTree                  |            | 1.8    | ms   |
| Challenge-response       | PUF = OFF  | 25     | ms   |
|                          | PUF = ON   | 7      | ms   |
| ECC point multiplication |            | 590    | ms   |
| ECC point addition       |            | 8      | ms   |

1. Using cypher block chaining (CBC) mode.

## 2.3.19 Crystal Oscillator

The following table describes the electrical characteristics of the crystal oscillator in the IGLOO2 FPGA and SmartFusion2 SoC FPGAs.

**Table 277 • Electrical Characteristics of the Crystal Oscillator – High Gain Mode (20 MHz)**

| Parameter                                   | Symbol     | Min                 | Typ   | Max                 | Unit | Condition                                |
|---------------------------------------------|------------|---------------------|-------|---------------------|------|------------------------------------------|
| Operating frequency                         | FXTAL      |                     | 20    |                     | MHz  |                                          |
| Accuracy                                    | ACCXTAL    |                     |       | 0.0047              | %    | 005, 010, 025, 050, 060, and 090 devices |
|                                             |            |                     |       | 0.0058              | %    | 150 devices                              |
| Output duty cycle                           | CYCXTAL    |                     | 49–51 | 47–53               | %    |                                          |
| Output period jitter (peak to peak)         | JITPERXTAL |                     | 200   | 300                 | ps   |                                          |
| Output cycle to cycle jitter (peak to peak) | JITCYCXTAL |                     | 200   | 300                 | ps   | 010, 025, 050, and 060 devices           |
|                                             |            |                     | 250   | 410                 | ps   | 150 devices                              |
|                                             |            |                     | 250   | 550                 | ps   | 005 and 090 devices                      |
| Operating current                           | IDYNXTAL   |                     | 1.5   |                     | mA   | 010, 050, and 060 devices                |
|                                             |            |                     | 1.65  |                     | mA   | 005, 025, 090, and 150 devices           |
| Input logic level high                      | VIHXTAL    | 0.9 V <sub>PP</sub> |       |                     | V    |                                          |
| Input logic level low                       | VILXTAL    |                     |       | 0.1 V <sub>PP</sub> | V    |                                          |

The following table lists the receiver pa in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 297 • Receiver Parameters**

| Symbol               | Description                                                           | Min   | Typ   | Max   | Unit          |
|----------------------|-----------------------------------------------------------------------|-------|-------|-------|---------------|
| VRX-IN-PP-CC         | Differential input peak-to-peak sensitivity (2.5 Gbps)                | 0.238 |       | 1.2   | V             |
|                      | Differential input peak-to-peak sensitivity (2.5 Gbps, de-emphasized) | 0.219 |       | 1.2   | V             |
|                      | Differential input peak-to-peak sensitivity (5.0 Gbps)                | 0.300 |       | 1.2   | V             |
|                      | Differential input peak-to-peak sensitivity (5.0 Gbps, de-emphasized) | 0.300 |       | 1.2   | V             |
| VRX-CM-AC-P          | Input common mode range (AC coupled)                                  |       |       | 150   | mV            |
| ZRX-DIFF-DC          | Differential input termination                                        | 80    | 100   | 120   | $\Omega$      |
| REXT                 | External calibration resistor                                         | 1,188 | 1,200 | 1,212 | $\Omega$      |
| CDR-LOCK-RST         | CDR relock time from reset                                            |       |       | 15    | $\mu\text{s}$ |
| RLRX-DIFF            | Return loss differential mode (2.5 Gbps)                              | -10   |       |       | dB            |
|                      | Return loss differential mode (5.0 Gbps)                              |       |       |       |               |
|                      | 0.05 GHz to 1.25 GHz                                                  | -10   |       |       | dB            |
|                      | 1.25 GHz to 2.5 GHz                                                   | -8    |       |       | dB            |
| RLRX-CM              | Return loss common mode (2.5 Gbps, 5.0 Gbps)                          | -6    |       |       | dB            |
| RX-CID <sup>1</sup>  | CID limit PCIe Gen1/2                                                 |       |       | 200   | UI            |
| VRX-IDLE-DET-DIFF-PP | Signal detect limit                                                   | 65    |       | 175   | mV            |

1. AC-coupled, BER =  $e^{-12}$ , using synchronous clock.

**Table 298 • SerDes Protocol Compliance**

| Protocol     | Maximum Data Rate (Gbps) | -1  | -Std |
|--------------|--------------------------|-----|------|
| PCIe Gen 1   | 2.5                      | Yes | Yes  |
| PCIe Gen 2   | 5.0                      | Yes |      |
| XAUI         | 3.125                    | Yes |      |
| Generic EPCS | 3.2                      | Yes |      |
| Generic EPCS | 2.5                      | Yes | Yes  |

The following table lists the SerDes reference clock AC specifications in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 299 • SerDes Reference Clock AC Specifications**

| Parameter                       | Symbol        | Min  | Max  | Unit |
|---------------------------------|---------------|------|------|------|
| Reference clock frequency       | $F_{REFCLK}$  | 100  | 160  | MHz  |
| Reference clock rise time       | $T_{RISE}$    | 0.6  | 4    | V/ns |
| Reference clock fall time       | $T_{FALL}$    | 0.6  | 4    | V/ns |
| Reference clock duty cycle      | $T_{CYC}$     | 40   | 60   | %    |
| Reference clock mismatch        | $M_{MREFCLK}$ | -300 | 300  | ppm  |
| Reference spread spectrum clock | $SSC_{ref}$   | 0    | 5000 | ppm  |

**Table 300 • HCSL Minimum and Maximum DC Input Levels (Applicable to SerDes REFCLK Only)**

| Parameter                                      | Symbol      | Min   | Typ | Max   | Unit |
|------------------------------------------------|-------------|-------|-----|-------|------|
| <b>Recommended DC Operating Conditions</b>     |             |       |     |       |      |
| Supply voltage                                 | $V_{DDI}$   | 2.375 | 2.5 | 2.625 | V    |
| <b>HCSL DC Input Voltage Specification</b>     |             |       |     |       |      |
| DC Input voltage                               | $V_I$       | 0     |     | 2.625 | V    |
| <b>HCSL Differential Voltage Specification</b> |             |       |     |       |      |
| Input common mode voltage                      | $V_{ICM}$   | 0.05  |     | 2.4   | V    |
| Input differential voltage                     | $V_{IDIFF}$ | 100   |     | 1100  | mV   |

**Table 301 • HCSL Minimum and Maximum AC Switching Speeds (Applicable to SerDes REFCLK Only)**

| Parameter                             | Symbol    | Min | Typ | Max | Unit     |
|---------------------------------------|-----------|-----|-----|-----|----------|
| <b>HCSL AC Specifications</b>         |           |     |     |     |          |
| Maximum data rate (for MSIO I/O bank) | $F_{MAX}$ |     |     | 350 | Mbps     |
| <b>HCSL Impedance Specifications</b>  |           |     |     |     |          |
| Termination resistance                | $R_t$     |     | 100 |     | $\Omega$ |

## 2.3.31 SmartFusion2 Specifications

### 2.3.31.1 MSS Clock Frequency

The following table lists the maximum frequency for MSS main clock in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 302 • Maximum Frequency for MSS Main Clock**

| Symbol | Description                              | -1  | -Std | Unit |
|--------|------------------------------------------|-----|------|------|
| M3_CLK | Maximum frequency for the MSS main clock | 166 | 142  | MHz  |

**Table 310 • SPI Characteristics for All Devices (continued)**

| Symbol                                                                   | Description                                                                      | Min                         | Typ   | Max | Unit | Conditions                                                                                                         |
|--------------------------------------------------------------------------|----------------------------------------------------------------------------------|-----------------------------|-------|-----|------|--------------------------------------------------------------------------------------------------------------------|
| sp2                                                                      | SPI_[0 1]_CLK minimum pulse width high                                           |                             |       |     |      |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/2                                                           | 6                           |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/4                                                           | 12.05                       |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/8                                                           | 24.1                        |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/16                                                          | 0.05                        |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/32                                                          | 0.095                       |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/64                                                          | 0.195                       |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/128                                                         | 0.385                       |       |     | µs   |                                                                                                                    |
| sp3                                                                      | SPI_[0 1]_CLK minimum pulse width low                                            |                             |       |     |      |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/2                                                           | 6                           |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/4                                                           | 12.05                       |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/8                                                           | 24.1                        |       |     | ns   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/16                                                          | 0.05                        |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/32                                                          | 0.095                       |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/64                                                          | 0.195                       |       |     | µs   |                                                                                                                    |
|                                                                          | SPI_[0 1]_CLK = PCLK/128                                                         | 0.385                       |       |     | µs   |                                                                                                                    |
| sp4                                                                      | SPI_[0 1]_CLK,<br>SPI_[0 1]_DO, SPI_[0 1]_SS<br>rise time (10%–90%) <sup>1</sup> |                             | 2.77  |     | ns   | I/O Configuration:<br>LVCMOS 2.5 V -<br>8 mA<br>AC loading: 35 pF<br>test conditions:<br>Typical voltage,<br>25 °C |
| sp5                                                                      | SPI_[0 1]_CLK,<br>SPI_[0 1]_DO, SPI_[0 1]_SS<br>fall time (10%–90%) <sup>1</sup> |                             | 2.906 |     | ns   | I/O Configuration:<br>LVCMOS 2.5 V -<br>8 mA<br>AC loading: 35 pF<br>test conditions:<br>Typical voltage,<br>25 °C |
| SPI master configuration (applicable for 005, 010, 025, and 050 devices) |                                                                                  |                             |       |     |      |                                                                                                                    |
| sp6m                                                                     | SPI_[0 1]_DO setup time <sup>2</sup>                                             | (SPI_x_CLK_period/2) – 8.0  |       |     | ns   |                                                                                                                    |
| sp7m                                                                     | SPI_[0 1]_DO hold time <sup>2</sup>                                              | (SPI_x_CLK_period/2) – 2.5  |       |     | ns   |                                                                                                                    |
| sp8m                                                                     | SPI_[0 1]_DI setup time <sup>2</sup>                                             | 12                          |       |     | ns   |                                                                                                                    |
| sp9m                                                                     | SPI_[0 1]_DI hold time <sup>2</sup>                                              | 2.5                         |       |     | ns   |                                                                                                                    |
| SPI slave configuration (applicable for 005, 010, 025, and 050 devices)  |                                                                                  |                             |       |     |      |                                                                                                                    |
| sp6s                                                                     | SPI_[0 1]_DO setup time <sup>2</sup>                                             | (SPI_x_CLK_period/2) – 17.0 |       |     | ns   |                                                                                                                    |
| sp7s                                                                     | SPI_[0 1]_DO hold time <sup>2</sup>                                              | (SPI_x_CLK_period/2) + 3.0  |       |     | ns   |                                                                                                                    |
| sp8s                                                                     | SPI_[0 1]_DI setup time <sup>2</sup>                                             | 2                           |       |     | ns   |                                                                                                                    |
| sp9s                                                                     | SPI_[0 1]_DI hold time <sup>2</sup>                                              | 7                           |       |     | ns   |                                                                                                                    |